

isc Silicon PNP Power Transistor

MJB42C

DESCRIPTION

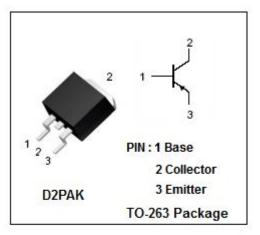
- Lead formed for surface mount applications(NO suffix)
- Electrically the same as TIP42 series
- Pb-free package are available
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

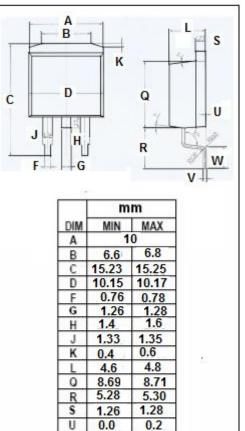
APPLICATIONS

· General purpose amplifier and switching applications



SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	-100	V
V _{CEO}	Collector-Emitter Voltage	-100	V
V _{EBO}	Emitter-Base Voltage	-5	V
Ιc	Collector Current-Continuous	-6	А
I _{CP}	Collector Current-Pulse	-10	A
I _B	Base Current	-2	А
Pc	Total Power Dissipation @ Ta=25℃	2	W
Pc	Total Power Dissipation @ Tc=25℃	65	W
TJ	Junction Temperature	-65~150	°C
T _{stg}	Storage Temperature Range	-65~150	°C





isc website: <u>www.iscsemi.com</u>

v

W

0.37

2.80

0.39

2.82



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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
V _{(BR)CEO} *	Collector-Emitter Breakdown Voltage	I _C =- 30mA; I _B = 0	-100			V
V _{CE(sat)*}	Collector-Emitter Saturation Voltage	I _C =-6A; I _B = -600mA			-1.5	V
$V_{\text{BE}(\text{on})^{*}}$	Base-Emitter On Voltage	Ic=- 6A; Vce=-4V			-2.0	V
I _{CEO}	Collector Cutoff Current	V_{CE} =-60V; I _E = 0			-0.7	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} =-5V; I _C = 0			-50	uA
h _{FE1*}	DC Current Gain	Ic= -0.3A; Vce= -4 V	30			
h _{FE2*}	DC Current Gain	I _C =- 3A; V _{CE} = -4 V	15		75	
f⊤	Current-Gain—Bandwidth Product	Ic= -0.5A; Vce= -10V		3		MHz

*:Pulse test PW≤300us,duty cycle≤2%

NOTICE:

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